

Notice of References Cited	Application/Control No. 10/074,564	Applicant(s)/Patent Under Reexamination TODD ET AL.	
	Examiner Brook Kebede	Art Unit 2823	Page 1 of 1

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	A	US-5,389,398 ✓	02-1995	Suzuki et al.	427/130
	B	US-5,698,771 ✓	12-1997	Shields et al.	73/31.05
	C	US-6,228,181	05-2001	Yamamoto et al.	148/33.5
	D	US-6,326,311 ✓	12-2001	Ueda et al.	438/694
	E	US-6,455,892 ✓	09-2002	Okuno et al.	257/328
	F	US-6,613,695 ✓	09-2003	Pomarede et al.	438/767
	G	US-			
	H	US-			
	I	US-			
	J	US-			
	K	US-			
	L	US-			
	M	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
	O					
	P					
	Q					
	R					
	S					
	T					

NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Ikoma et al., Growth of Si/3C-SiC/Si(100) hetrostructures by pulsed supersonic free jets, Applied Physics Letters, Volume 75, No. 25, Pp. 3977-3979, December 1999. ✓
	V	
	W	
	X	

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
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